



CMKD2836  
CMKD2838

SURFACE MOUNT ULTRAmi™  
DUAL PAIR  
HIGH SPEED SILICON  
SWITCHING DIODES

ULTRAmi™



SOT-363 CASE

The following configurations are available:

CMKD2836 DUAL PAIR, COMMON ANODE  
CMKD2838 DUAL PAIR, COMMON CATHODE

**MAXIMUM RATINGS:** ( $T_A=25^\circ\text{C}$ )

Peak Repetitive Reverse Voltage	$V_{RRM}$	75	V
Average Forward Current	$I_O$	200	mA
Peak Forward Current	$I_{FM}$	300	mA
Power Dissipation	$P_D$	350	mW
Operating and Storage Junction Temperature	$T_J, T_{stg}$	-65 to +150	°C
Thermal Resistance	$\Theta_{JA}$	357	°C/W

**MARKING CODE: K36**

**MARKING CODE: K38**

SYMBOL		UNITS
$V_{RRM}$	75	V
$I_O$	200	mA
$I_{FM}$	300	mA
$P_D$	350	mW
$T_J, T_{stg}$	-65 to +150	°C
$\Theta_{JA}$	357	°C/W

**ELECTRICAL CHARACTERISTICS PER DIODE:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
$I_R$	$V_R=50\text{V}$			100	nA
$BV_R$	$I_R=100\mu\text{A}$	75			V
$V_F$	$I_F=10\text{mA}$			1.0	V
$V_F$	$I_F=50\text{mA}$			1.0	V
$V_F$	$I_F=100\text{mA}$			1.2	V
$C_T$	$V_R=0, f=1.0\text{MHz}$		1.5	4.0	pF
$t_{rr}$	$I_R=10\text{mA}, R_L=100\Omega, \text{Rec. to } 1.0\text{mA}$			4.0	ns

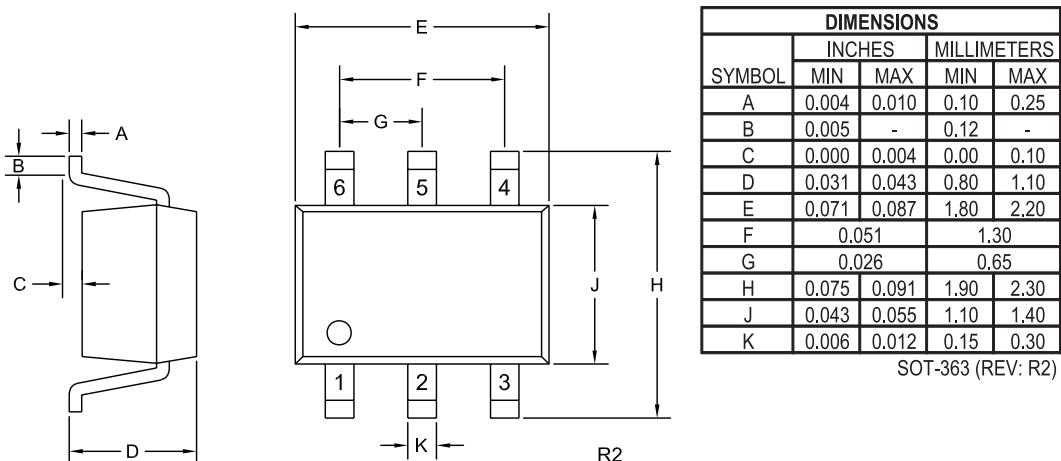
**Central**™  
Semiconductor Corp.

**DESCRIPTION:**

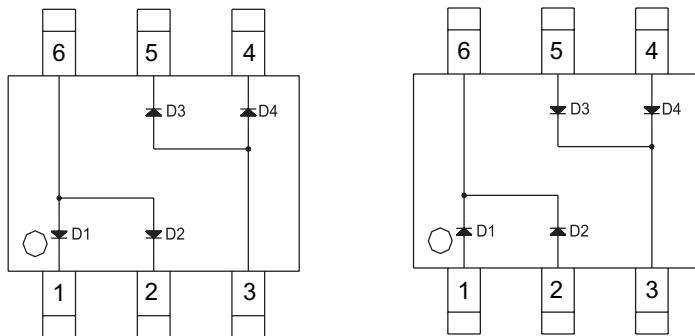
The CENTRAL SEMICONDUCTOR CMKD2836 and CMKD2838 types consist of four high speed switching diodes arranged in two electrically isolated configurations (Common Anode and Common Cathode). These devices are manufactured by the epitaxial planar process, in an epoxy molded ULTRAmi™ surface mount package, designed for high speed switching applications.

SURFACE MOUNT ULTRAMini™  
DUAL PAIR  
HIGH SPEED SILICON  
SWITCHING DIODES

SOT-363 CASE - MECHANICAL OUTLINE



PIN CONFIGURATIONS



CMKD2836

CMKD2838

LEAD CODE:

- 1) CATHODE D1
- 2) CATHODE D2
- 3) ANODE D3, D4
- 4) CATHODE D4
- 5) CATHODE D3
- 6) ANODE D1, D2

MARKING CODE: K36

LEAD CODE:

- 1) ANODE D1
- 2) ANODE D2
- 3) CATHODE D3, D4
- 4) ANODE D4
- 5) ANODE D3
- 6) CATHODE D1, D2

MARKING CODE: K38